Analog Power AM7336N

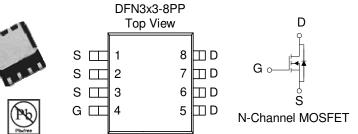
N-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low $r_{DS(on)} provides higher efficiency and $
	extends battery life

- Low thermal impedance copper leadframe DFN3x3-8PP saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)} m(\Omega)$	$I_{D}(A)$		
20	9 @ $V_{GS} = 4.5V$	17		
30	11 @ $V_{GS} = 2.5V$	15		



ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter			Limit	Units	
Drain-Source Voltage			30	V	
Gate-Source Voltage	V_{GS}	±8	V		
Continuous Drain Current ^a	T _A =25°C	Τ_	±17		
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	ъ	±12	Α	
Pulsed Drain Current ^b			±40		
Continuous Source Current (Diode Conduction) ^a		I_S	2	A	
	$T_A=25^{\circ}C$	D	3.5	W	
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	P_{D}	2	l vv	
Operating Junction and Storage Temperature Range			-55 to 150	°C	

HALOGEN FREE

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Units	
Maximum Junction-to-Case ^a	t <= 5 sec	$R_{ heta JC}$	25	°C/W	
Maximum Junction-to-Ambient ^a	t <= 5 sec	$R_{ heta JA}$	50	°C/W	

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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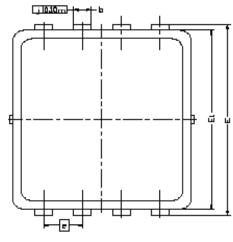
-			Limits				
Parameter	Symbol	Symbol Test Conditions		Тур	Max	Unit	
Static					•		
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	1		3	V	
Gate-Body Leakage	Igss	$V_{DS} = 0 \text{ V}, V_{GS} = 8 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate voltage Drain Current	1088	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current ^A	$I_{D(on)}$	$V_{\rm DS} = 5 \text{ V}, V_{\rm GS} = 10 \text{ V}$	20			A	
D : G O D : A		$V_{GS} = 4.5 \text{ V}, I_{D} = 2 \text{ A}$			9	mO	
Drain-Source On-Resistance ^A	r _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 2 \text{ A}$			11.0	mΩ	
Forward Tranconductance ^A	gfs	$V_{DS} = 15 \text{ V}, I_{D} = 10 \text{ A}$		40		S	
Diode Forward Voltage	V_{SD}	$I_S = 2.3 \text{ A}, V_{GS} = 0 \text{ V}$		0.7		V	
Dynamic ^b							
Total Gate Charge	Qg	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_{D} = 10 \text{ A}$		11		nC	
Gate-Source Charge	Q_{gs}			6			
Gate-Drain Charge	Q_{gd}	ID = 10 A		4		7	
Input Capacitance	Ciss	N 15NN ON 6		1302			
Output Capacitance	Coss	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V},$ f $= 1 \text{MHz}$		423		pF	
Reverse Transfer Capacitance	Crss			171			
Turn-On Delay Time	t _{d(on)}			10			
Rise Time	t _r	$V_{\rm DD}$ = 25 V, R_L = 25 Ω , I_D = 1 A,		5		nS	
Turn-Off Delay Time	t _{d(off)}	$V_{GEN} = 10 \text{ V}$		22		113	
Fall-Time	tf			4			

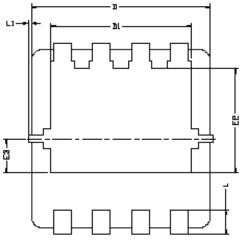
Notes

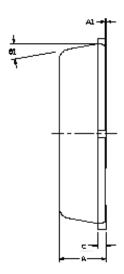
- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information







DIM.	MILLIMETERS			INCHES			
יויונת	MIN	NOM	MAX	MIN	NDM	MAX	
Α	0,700	0'80	0.900	0.0276	0.0315	0.0354	
A1	0.00	-	0.05	0.000		0.002	
la	0.24	0.30	0.35	0.009	0.012	0.014	
C	0.10	0.152	0,25	0,004	0,006	0,010	
ם	(3	3.00 BSC			0.118 BSC		
D1	2.35 B2C			a.	093 BS	C 2	
Ε	3,20 BSC			0.	126 BS)C	
E1	3.00 BSC			٥	.118 BS	C	
E5	1	1.75 BSC			0.069 BSC		
E3	0.575 BSC			0.	023 BS	C.	
6	0.65 BSC			O.	026 BS	C 2	
L	0,30	0,40	0,50	0.0118	0.0157	0.0197	
L1			0.100	D		0.004	
91	٥°	10*	12*	0*	10°	12*	